ASSP

CMOS

20 MHz 10-bit A/D Converter

MB40C360

DESCRIPTION

MB40C360 is a high-speed A/D converter using a fast CMOS technology.

: 10 bits

: ±1.0 LSB (max.)

: Single +3.0 V

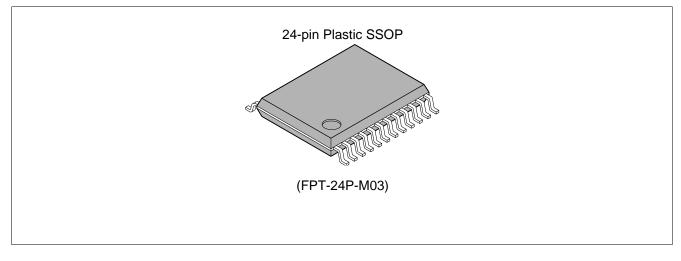
■ FEATURES

- Resolution
- Differential linearity error
- Maximum conversion rate : 20 MSPS (min.)
- Supply voltage
- Digital in/output voltage : 3 V CMOS level (tristate)
- Analog input voltage range : 0 V to AV_{DD} (1.5 V to 2.1 Vp-p)
- Analog input capacitance : 18 pF (standard)
- Dissipation power
- Additional capabilities
- : Power saving function tristate output
- : 24-pin SSOP

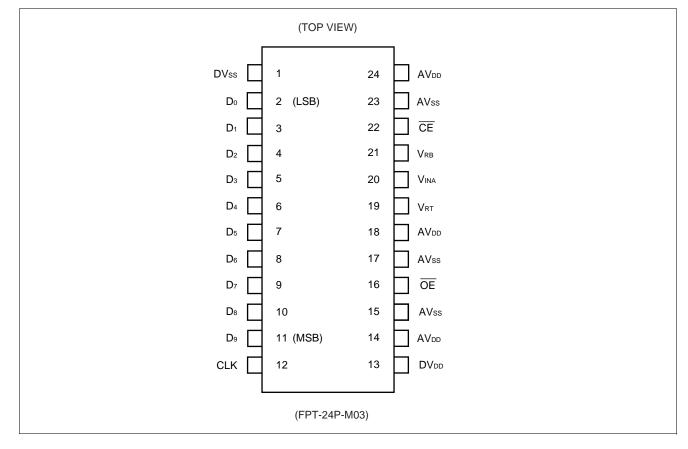
: 40 mW

PACKAGE

Package



■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Symbol	Description
14, 18, 24	AVdd	Analog power supply (+3.0 V)
13	DVdd	Digital power supply (+3.0 V)
15, 17, 23	AVss	Analog power supply ground pin (0 V)
1	DVss	Digital power supply ground pin (0 V)
2, 3, 4, 5, 6 7, 8, 9, 10, 11	D ₀ to D ₉	Digital output pin (D₀: LSB, D₀: MSB)
12	CLK	Clock input pin (3 V CMOS input)
20	Vina	A/D converter analog input pin Input range is VRB to VRT (0 V to 2.0 V: standard)
19	Vrt	Reference voltage input pin on top side (2.0 V: standard)
21	Vrb	Reference voltage input pin on bottom side (0 V: standard)
22	CE	Chip enable input pin Input high signal brings standby state. Input low signal brings operation state.
16	OE	Output enable input pin Input high signal readies digital output high-impedance state. Input low signal induces digital output state.

Note: The values in parentheses are standard.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rat	Unit	
Falameter	Symbol	Min.	Max.	Unit
Power supply voltage	AVdd, DVdd	-0.3	+4.0	V
Input voltage (analog/digital)	$\begin{array}{c} CLK,V_{INA},V_{RT},V_{RB},\\ \hline \mathbf{CE},\overline{\mathbf{OE}} \end{array}$	-0.3	AV _{DD} + 0.3*	V
Output voltage	D ₀ to D ₉	-0.3	DVDD + 0.3*	V
Storage temperature	Tstg	-55	+125	°C

* : Don't exceed 4.0V

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Baramatar	Symbol	Value			Unit	
Parameter	Symbol	Min.	Тур.	Max.	Unit	
	AVdd	2.70	3.00	3.60	V	
Power supply voltage	DVdd	2.70	3.00	3.60	V	
	AVdd – DVdd	0.0	—	0.2	V	
Analog input voltage	VINA	Vrb	_	Vrt	V	
Analog reference voltage: T	Vrt	1.5	2.0	AVdd	V	
Analog reference voltage: B	Vrb	0.0	—	AVpd-1.5	V	
Analog reference voltage range	Vrt – Vrb	1.5	2.0	2.1	V	
Digital "H" level input voltage	Vihd	2.3	_	DVdd	V	
Digital "L" level input voltage	Vild	0	—	0.5	V	
Digital input current	lıd	_	_	5	μΑ	
Clock frequency	fclк	0.5	_	20	MHz	
"H" level minimum clock pulse width	tw +	20.0	—	—	ns	
"L" level minimum clock pulse width	tw -	20.0	—	—	ns	
Operating temperature range	Та	-20	—	+70	°C	

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

Analog Section

$(AV_{DD} = 2.7 V to)$	3.6 V, DV _{DD} = 2.7 V to 3.6	$V, V_{RT} = 2.0 V, V_{RB} = 0$	V, Ta = -20° C to $+70^{\circ}$ C)
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Parameter		Symbol	Value			Unit
			Min.	Тур.	Max.	Unit
Resolution		RES	—	10	—	bit
Linearity error	DC precision	LE	—	±1.00	±2.00	LSB
Differential linearity error	DC precision	DLE	—	±0.50	±1.00	LSB
Analog input capacity	Analog input capacity		—	18		pF
Analog "H" level input current		IIHA*1	—	200		μA
Analog "L" level input current		IILA ^{*2}	—	-250		μΑ
Analog input bandwidth (–0.5 dB)		fвw	_	20		MHz
Reference current (BOTTOM side)		Iгв	3.0	6.0	10.0	mA
Analog supply current		Aldd	_	13.0	40.0	mA
Digital supply current		DIDD	—	1.5	4.0	mA
Standby supply current		ISTBA	—	100		μA
		ISTBD		5	_	μΑ

*1: $V_{INA} = 2.0 V$

*2: VINA = 0.0 V

• Digital Section

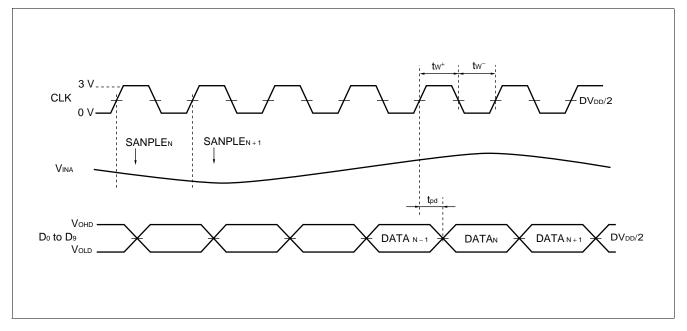
Parameter	Symbol	Value			Unit
Falanielei		Min.	Тур.	Max.	Unit
Digital "H" level output voltage	Vонd	2.5	_	DVdd	V
Digital "L" level output voltage	Vold	0	—	0.4	V
Digital "H" level output current	Іонд	-400	—		μA
Digital "L" level output current	lold	—	—	1.6	mA

• Switching Section

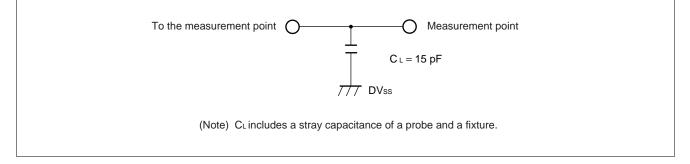
(AV_{DD} = 2.7 V to 3.6 V, DV_{DD} = 2.7 V to 3.6 V, V_{RT} = 2.0 V, V_{RB} = 0 V, Ta = -20°C to +70°C)

Parameter	Symbol		Unit		
Farameter		Min.	Тур.	Max.	Unit
Maximum conversion rate	fs	20	—	_	MSPS
Digital output delay time	t _{pd}	1	6	15	ns

■ DIAGRAM



■ DIGITAL OUTPUT BUFFER LOAD CIRCUIT



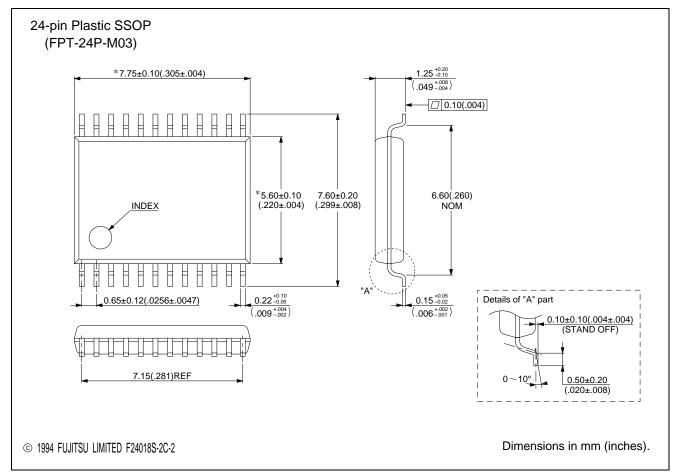
■ USAGE PRECAUTIONS

- Be sure to ground the pins of AV_{DD}, DV_{DD}, V_{RT} and V_{RB} via high-frequency capacitor. Place the high-frequency capacitor as close as possible to the pin.
- You can minimize the power supply current dissipation due to the internal logic indetermination by making the clock to 4CLK or higher.

ORDERING INFORMATION

Part number	Package	Remark
MB40C360PFV	24-pin Plastic SSOP (FPT-24P-M03)	

■ PACKAGE DIMENSION



MB40C360

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